# Journal of Materials Chemistry A



# **PAPER**

View Article Online
View Journal | View Issue



Cite this: J. Mater. Chem. A, 2024, 12, 15440

# Phase engineering to construct In<sub>2</sub>S<sub>3</sub> heterophase junctions and abundant active boundaries and surfaces for efficient Pyro-PEC performance in CdS/In<sub>2</sub>S<sub>3</sub>†

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Metal sulfide photoelectrodes are considered as common catalysts for PEC water splitting, but their instability and carrier density limitations still restrict their applications. Phase modification plays a vital role in improving photocatalytic efficiency. Here, we successfully constructed In<sub>2</sub>S<sub>3</sub> heterophase junctions in CdS/In<sub>2</sub>S<sub>3</sub> heterojunctions by phase modulation engineering for efficient pyro-photoelectrochemical catalytic (Pyro-PEC) water splitting. The experimental results show that the CdS/In<sub>2</sub>S<sub>3</sub> generated by phase engineering displays a high current density of 3.52 mA cm<sup>-2</sup> at 1.23 V vs. RHE under the Pyro-PEC conditions, which is a 14.67-fold enhancement of bare CdS under the photoelectrocatalytic conditions, and exhibits a 63.98% bulk transport capacity, which is a 49.51% enhancement of bare CdS under photoelectrocatalytic conditions, and the stability also improved very well. This is due to the fact that photoelectrocatalytic conditions and heterophase junctions formed abundant phase boundaries and active surfaces to promote catalytic reactions, and enhanced the polarization force to optimize the pyroelectric performance, which ultimately achieved excellent pyro-photoelectrochemical performance. This work provides evidence for the effect of phase engineering on photoelectric and pyroelectric properties, and provides a simple and effective method for modulating the phase structure for photoanodes using hydrothermal methods.

Received 2nd March 2024 Accepted 6th May 2024

DOI: 10.1039/d4ta01455c

rsc.li/materials-a

# 1 Introduction

Researchers are continuously working to develop efficient, stable and sustainable energy systems to address the problems of limited conventional energy storage, which are harmful to the environment, and to reduce dependence on finite fossil fuel resources to meet the energy demand. 1-3 Hydrogen is a clean and renewable energy source, storing several times more energy per unit mass than fossil fuels, and can be used in industrial fuels, medical anesthesia, and transportation, which is crucial for promoting the energy transition.4-6 Photoelectrochemical (PEC) water splitting utilizes renewable energy sources, such as solar energy, to convert water into hydrogen for highly energy-dense storage and utilization.7 Semiconductors are an influential part of the PEC water splitting and can be categorized into n-type (α- $Fe_2O_3$ , 8-10 CdS, 11,12 BiVO<sub>4</sub> (ref. 13-15)) and p-type (Sb<sub>2</sub>S<sub>3</sub>, 16-18 CuFe<sub>2</sub>O<sub>4</sub>, <sup>19,20</sup> CuO (ref. 21–23)) semiconductors depending on the majority charge carriers. Ideal semiconductors are characterized by high light-absorbing capacity, stable chemical properties, and

good catalytic performance. CdS is a candidate for photoanode materials due to its good visible light response and suitable band

edge position. However, its stability and catalytic efficiency are

not satisfactory, and there are still some challenges.

cm<sup>-2</sup> at about 0.75 V.<sup>26</sup> Peng *et al.* regulated the charge migration mode by constructing CdS/MoS<sub>2</sub>, and the formation of MoS<sub>2</sub> in the surface layer not only enhanced the light absorption but also reduced the carrier recombination and optimized the carrier transport regime.<sup>27</sup> Chen *et al.* achieved a large hydrogen precipitation rate of 102.7 μmol h<sup>-1</sup> g<sup>-1</sup> by using deflected graphene (D-rGO) as a co-catalyst to enhance the catalytic activity and stability of CdS.<sup>28</sup> All these behaviors improved the properties of CdS but, unluckily, the limited success of these modification methods remains a matter of concern and new strategies are urgently needed.

It is worth emphasizing that increasing the energy source of the PEC system is an effective means to broaden the applications. In addition to light energy, heat energy from temperature

Researchers have put forward the concepts of defect modulation, heterojunction construction, and co-catalysts to enhance the performance of CdS.<sup>24–26</sup> For example, Wang *et al.* investigated the effect of different concentrations of Cu doping on the properties of CdS, and the current density increased to 3.16 mA cm<sup>-2</sup> at about 0.75 V.<sup>26</sup> Peng *et al.* regulated the charge migration mode by constructing CdS/MoS<sub>2</sub>, and the formation of

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<sup>†</sup> Electronic supplementary information (ESI) available. See DOI: https://doi.org/10.1039/d4ta01455c

differences is also worth utilizing.29-31 CdS as a pyroelectric material can effectively convert thermal energy into electrical energy, with the advantages of repeated utilization and wide temperature response range. Therefore, the photoelectrocatalytic (Pyro-PEC) system can increase the driving force of the catalytic system. Among pyroelectric materials, ferroelectrics are a special type of pyroelectric material in which internal spontaneous polarization promotes carrier separation to boost catalytic efficiency.32 Tetragonal-phase In2S3 is a ferroelectric with a large specific surface area that provides a large transfer path for carrier migration, while unsaturated covalent bonds and defects on the surface provide a high density of active sites, a forbidden bandwidth between 2.0 eV and 2.3 eV, and a wide range of light absorption, resulting in good PEC properties. 33,34 By constructing CdS/In<sub>2</sub>S<sub>3</sub> composites, not only the catalytic efficiency can be improved, but also the nontoxic In<sub>2</sub>S<sub>3</sub> covered on the surface of CdS can be used as a buffer layer to enhance the stability of the photoelectrode. However, under the influence of the complex lattice structure of the surface and the external environment, the ferroelectricity at the interface weakens or disappears thus affecting the pyroelectric properties of CdS/In<sub>2</sub>S<sub>3</sub>. Recently, phase engineering of metal sulfides has provided a new research direction, namely, to change the phase structure of polycrystalline materials under external stimuli, resulting in the formation of abundant heterophase junctions and boundaries. The phase structure plays an important role in the catalytic properties of semiconductors, affecting the carrier generation and transport processes, and hence their PEC and pyroelectric properties.35

In this paper, we firstly modulate the phase structure in CdS/ In<sub>2</sub>S<sub>3</sub> by a simple hydrothermal method and discuss the effect of phase engineering in the Pyro-PEC water splitting system in detail. This study provides an effective method for photoelectrode phase modulation to realize an efficient and stable Pyro-PEC water splitting system.

#### **Experimental section** 2

### **Fabrication of CdS**

In short, CdS nanorods were prepared by the hydrothermal method using cadmium nitrate (Cd(NO<sub>3</sub>)<sub>2</sub>), and thiourea (CH<sub>4</sub>N<sub>2</sub>S) as analytically pure reagents. Glutathione  $(C_{10}H_{17}N_3O_6S)$  of 0.018 mol L<sup>-1</sup> was added to 0.03 mol L<sup>-1</sup> solution of Cd(NO<sub>3</sub>)<sub>2</sub> and CH<sub>4</sub>N<sub>2</sub>S as an activator to promote the reaction. The solution was stirred thoroughly in a magnetic stirrer to promote full dissolution of the reagents with the onset of the reaction. After that, it was poured into a 25 mL Teflonlined stainless steel autoclave containing fluorine-doped tin oxide (FTO) glass and kept at 200 °C for 8 h. Finally, it was dried in a vacuum drying oven to obtain CdS nanorods.

#### 2.2 Fabrication of CdS/In<sub>2</sub>S<sub>3</sub>

Shortly, In<sub>2</sub>S<sub>3</sub> was prepared on the surface of CdS by a two-step hydrothermal method to form CdS/In<sub>2</sub>S<sub>3</sub> composites. After 100 mL of InCl<sub>3</sub>-4H<sub>2</sub>O at a concentration of 0.01 mol L<sup>-1</sup> and  $CH_4N_2S$  at a concentration of 0 0.0125 mol L<sup>-1</sup> were fully mixed,

the reaction mixture was fully stirred with a magnetic stirrer for 30 min to allow the reaction to fully occur. It was then poured into a 25 mL Teflon-lined stainless steel autoclave containing FTO glass with CdS samples, and kept at 200 °C for 4 h and 8 h to obtain CdS/In<sub>2</sub>S<sub>3</sub> with a tetragonal phase and both cubic and tetragonal phases referred to as CdS/In<sub>2</sub>S<sub>3</sub>-T and CdS/In<sub>2</sub>S<sub>3</sub>-TC, respectively.

#### 2.3 Characterization

The crystalline phase composition and crystal structure of the samples were characterized by XRD (D/Max-2500, Rigaku,  $2\theta =$ 10°-70°) using Cu K $\alpha$  radiation at  $\lambda = 0.15418$  nm. Characterization of the surface morphology of the photoelectrodes was performed by scanning electron microscopy (SEM, JEOL JSM-7800F). Detailed crystal morphology was characterized by transmission electron microscopy and high-resolution transmission electron microscopy, TEM and HRTEM (JEOL JEM 2100F) with energy dispersive spectroscopy (EDS). The energy shift and energy capture at the interfacial energy levels of the elements of the electrode materials were tested by X-ray photoelectron spectroscopy (XPS) using Al K $\alpha$  radiation ( $h\nu$  = 1486.6 eV) and the spectra were recorded on a Thermo ESCA-LAB250XI system. A DU-8B UV-vis double-beam spectrophotometer from 300 to 700 nm was used to obtain UV-vis absorbance spectra. An ultramicrowave photoelectron spectrometer (UPS), model Thermo ESCALAB 250XI, with an excitation voltage of -5 V, was used to measure the function of electrical energy, the conduction and the valence band position. Photoluminescence (PL) was estimated using a HITACHI: F-7000 fluorescence spectrometer at an excitation wavelength of 350 nm. Surface photovoltage detection (SPV) with a surface photovoltaic spectrometer (PL-SPS/IPCE1000) was achieved using monochromatic light (500 W xenon lamp). The ferroelectric domains of the samples were characterized by piezoelectric force microscopy (PFM) with a driving voltage of 0.5 V. Oxygen yield is analyzed using an all-glass automatic on-line trace gas analysis system (Labsolar 6A).

#### 3 Results and discussion

To confirm the phase type, X-ray diffraction (XRD) of different specimens was performed as shown in Fig. 1(a), where "•" indicates the diffraction peaks of FTO glass. From Fig. 1(a), it can be seen that the diffraction peaks of CdS can be well retrieved from the standard card 77-2306. The diffraction peaks detected at  $2\theta = 26.7^{\circ}$ ,  $2\theta = 24.8^{\circ}$ , and  $2\theta = 28.2^{\circ}$  correspond to (002), (100), and (101) respectively, and indicate the successful preparation of hexagonal CdS, the crystal morphology of which is shown in Fig. 1(b).36 In addition, tetragonal In2S3 diffraction peaks with high crystalline quality were found at  $2\theta = 27.43^{\circ}$ ,  $2\theta$  $= 28.25^{\circ}$ , and  $2\theta = 43.74^{\circ}$ , corresponding to (109), (0012), and (2212), respectively, which correspond well to the standard In<sub>2</sub>S<sub>3</sub> card 25-0390. The crystal structure of the tetragonal phase  $In_2S_3$  is shown in Fig. 1(c), where the lattice parameters  $\alpha = \beta =$  $\gamma = 90^{\circ}$ , a = b = 7.62, c = 32.36, confirming the successful complexation of tetragonal phase In<sub>2</sub>S<sub>3</sub> onto the CdS surface

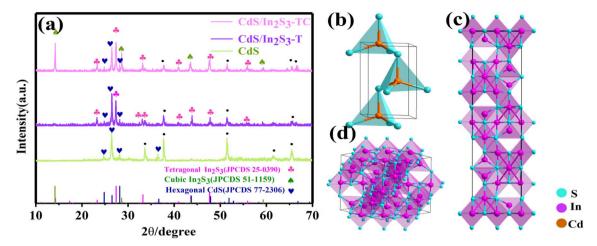


Fig. 1 (a) XRD patterns of CdS, CdS/In<sub>2</sub>S<sub>3</sub>-T and CdS/In<sub>2</sub>S<sub>3</sub>-TC, the crystal structure of hexagonal CdS (b), tetragonal In<sub>2</sub>S<sub>3</sub> (c), cubic In<sub>2</sub>S<sub>3</sub> (d).

(CdS/In<sub>2</sub>S<sub>3</sub>-T). With the extension of the hydrothermal treatment time to 8 h, new diffraction peaks appeared at  $2\theta = 14.16^{\circ}$ ,  $2\theta = 28.62^{\circ}$ , and  $2\theta = 43.56$ , corresponding to (111), (222), and (333), respectively, indicating the generation of In<sub>2</sub>S<sub>3</sub> in the cubic phase, and the crystal morphology of the In<sub>2</sub>S<sub>3</sub> in the cubic phase is shown in Fig. 1(d), where the lattice parameters  $\alpha=\beta=\gamma=90^{\circ}$ , a=b=c=10.77. The prolonged hydrothermal treatment time promotes the transformation of some structures from the tetragonal phase into the cubic phase, which proves the successful preparation of CdS/In<sub>2</sub>S<sub>3</sub> with abundant phase interfaces (CdS/In<sub>2</sub>S<sub>3</sub>-TC). By comparing the detailed lattice parameters, it can be seen that the cell edge length of the cubic phase is  $\sqrt{2}$  times longer than the diagonal at the bottom of the tetragonal structure in the tetragonal phase cell. This gives an idea of the growth mechanism: the cubic-phase cell grows diagonally along the bottom edge of the tetragonal-phase cell (Fig. S1†). There are natural defects in the In<sub>2</sub>S<sub>3</sub> tetragonal phase, such as in vacancies and other defects. In this experiment, due to the prolongation of hydrothermal treatment time, the atomic driving force is increased under high temperature and high pressure, and the violent movement of the atoms makes some of the vacancies orderly, resulting in the loss of symmetry in the spinel structure, and part of the tetragonal phase is transformed into the cubic phase with a symmetric structure.37

Morphology is part of the PEC performance of a photo-electrode and was characterized by SEM. Fig. 2(a) shows that CdS with a smooth surface and about 400 nm particle size is uniformly distributed and grown vertically on the FTO glass surface. When  $In_2S_3$  was grown on the surface of CdS after the second hydrothermal growth, wedge-shaped  $In_2S_3$  with a size of about 1.5–2  $\mu m$  was generated on the surface almost covering the CdS nanorods. On prolonging the reaction time, the size of CdS/In $_2S_3$ -TC nanoparticles decreased dramatically to about 1  $\mu m$ . The pore size distribution and BET specific surface area can be obtained by the nitrogen adsorption technique. The BET surface areas were about 0.81 m $^2$  g $^{-1}$  for CdS and 2.16 m $^2$  g $^{-1}$  for CdS/In $_2S_3$ -T, while that of CdS/In $_2S_3$ -TC significantly increased

to 3.55 m $^2$  g $^{-1}$ . The pore distributions were as shown in Fig. S2,† and the pore size of CdS was about 10 nm. The pore size of of CdS/In<sub>2</sub>S<sub>3</sub>-T further decreased, while that of CdS/In<sub>2</sub>S<sub>3</sub>-TC decreased to around 8 nm. Detailed structural and crystallographic features of CdS/In<sub>2</sub>S<sub>3</sub>-TC are represented by TEM and HRTEM (Fig. 2(d-f)). The high-resolution TEM image in Fig. 2(d) shows the successful contact of CdS with In<sub>2</sub>S<sub>3</sub>. Fig. 2(e) shows the clear and continuous lattice stripes of the three phases, showing more exposed surfaces, including preferred growth surfaces for the three different phases, with (002) for the hexagonal phase of CdS, (109) for the tetragonal phase of I<sub>2</sub>S<sub>3</sub>, and (111) for the cubic phase of In<sub>2</sub>S<sub>3</sub>, which is in good agreement with the XRD test results. To further verify the successful attachment of In<sub>2</sub>S<sub>3</sub> with different phase structures to the CdS surface, the contents of elements in CdS/In<sub>2</sub>S<sub>3</sub>-TC analyzed by EDS spectroscopic analysis with elemental distribution maps are shown in Fig. 2(f). The three elements In, S, and Cd are successfully and homogeneously distributed in CdS/In<sub>2</sub>S<sub>3</sub>-TC.

Any change between atoms leads to a change in bonding energy and a shift in energy levels. Therefore, the effect of phase engineering on the elemental state and energy capture at the electrode material interface was tested by XPS.38 Before analysis, the binding energy was corrected with C 1s (284.8 eV). In addition to the peaks of C and O arising from unconfirmed sources of carbon and oxygen in Fig. 3(a), XPS spectra detected S, Cd, and In, which coincide with the elements studied in this paper. From the high-resolution XPS spectra in Fig. 3(b-d), it can be seen that in CdS/In<sub>2</sub>S<sub>3</sub>-T, the  $2p_{3/2}$  eV and  $2p_{1/2}$  eV peaks of S were detected at 160.83 eV and 162.03 eV, respectively. The 3d<sub>5/2</sub> and 3d<sub>3/2</sub> peaks of In were detected at 444.53 eV and 452.08 eV, and the Cd  $3d_{5/2}$  and Cd  $3d_{3/2}$  peaks were seen at 405.10 eV and 411.80 eV. Whereas in CdS/ $In_2S_3$ -TC, the  $2p_{3/2}$ and  $2p_{1/2}$  peaks appeared at 161.29 eV and 162.54 eV, the  $3d_{5/2}$ and 3d<sub>3/2</sub> peaks of In were detected at 444.83 eV and 452.38 eV, and the peaks of Cd  $3d_{5/2}$  and Cd  $3d_{3/2}$  appeared at 405.30 eV and 412.00 eV. It follows that the phase modulation increases the bonding forces between atoms and appears to change the electronic environment. The shielding charge in CdS/In<sub>2</sub>S<sub>3</sub>-T

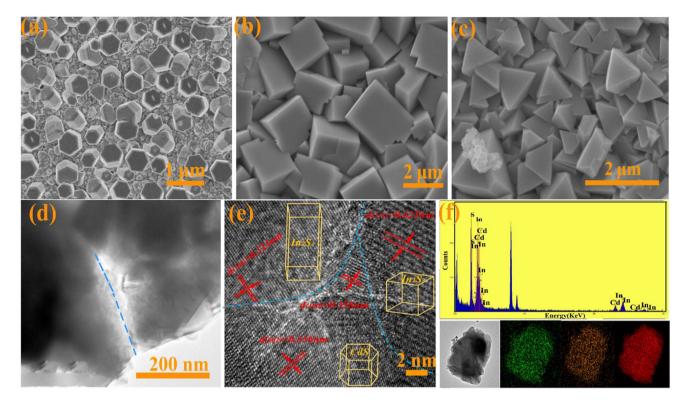


Fig. 2 SEM patterns of CdS (a), CdS/In<sub>2</sub>S<sub>3</sub>-TC (b) and CdS/In<sub>2</sub>S<sub>3</sub>-TC (c), TEM of CdS/In<sub>2</sub>S<sub>3</sub>-TC (d), HRTEM of CdS/In<sub>2</sub>S<sub>3</sub>-TC (e), EDS patterns and mapping images of CdS/In<sub>2</sub>S<sub>3</sub>-TC (f).

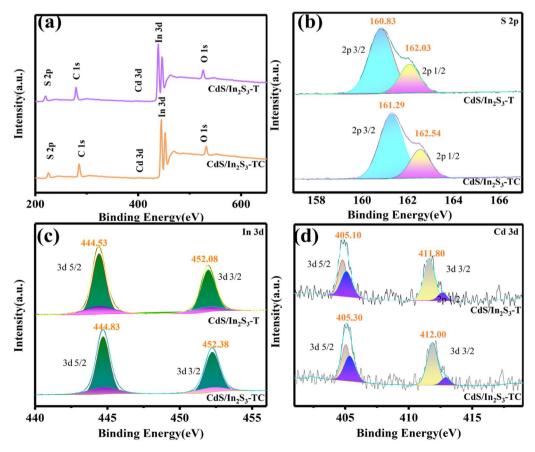


Fig. 3 (a) XPS spectra of CdS/In<sub>2</sub>S<sub>3</sub>-T and CdS/In<sub>2</sub>S<sub>3</sub>-TC, and the related high-resolution spectra of S 2p, Cd 3d and In 3d (b-d).

reduces the surface crystal potential due to the critical size effect, while  $CdS/In_2S_3$ -TC, which is not a polarized cubic phase, weakens the phenomenon of the disappearance of surface polarity brought about by the surface shielding charge and increases the surface bonding force.

Fig. 4(a) shows the UV-vis absorption spectra of different photoelectrodes used to characterize the absorption capacity of light energy in photoelectrocatalytic systems. The intersection of the tangent line of the curve and the horizontal coordinate is the absorption edge, and the absorption edge of CdS locates at 516 nm, and CdS/In<sub>2</sub>S<sub>3</sub>-T locates at 551 nm, indicating that with the formation of the In<sub>2</sub>S<sub>3</sub>, the light-absorbing ability increases effectively. In addition, the absorption edge of CdS/In<sub>2</sub>S<sub>3</sub>-TC is redshifted, showing a stronger light-absorbing ability, which is having a larger surface area to form a larger light-absorbing surface. The Tauc plots of the samples were calculated from egn (S1),†39 and the forbidden bandwidth of CdS is at 2.40 eV, which is in agreement with the previous report. The forbidden bandwidth of CdS/In<sub>2</sub>S<sub>3</sub>-TC is 2.16 eV, which is reduced by 0.09 eV compared with that of CdS/In<sub>2</sub>S<sub>3</sub>-T, which suggests that the composites expose more light-absorbing surfaces to optimize the light-absorbing ability of the semiconductor. The baseband edge positions of the valence band (VB) and conduction band (CB) are determined in conjunction with UPS. Fig. 4(b) shows the cutoff energy  $(E_{\text{cutoff}})$  and onset energy (E<sub>onset</sub>) for CdS, In<sub>2</sub>S<sub>3</sub> and CdS/In<sub>2</sub>S<sub>3</sub>-TC. According to eqn (S2)-(S4), $\dagger^{40}$  the position of the  $E_{\rm CB}$  and  $E_{\rm VB}$  can be calculated. The energy band diagrams of samples based on band gap and UPS are shown in Fig. 4(c) which suggests that the formation of  $CdS/In_2S_3$  composites with a multi-phase structure enhances the light absorption capacity.<sup>41</sup>

PL is also another key characterization of light absorption ability. After excitation with a light source of 320 nm, a portion of free carriers will recombine, leading to the process of photoluminescence. The smaller the PL value, the lower the degree of carrier recombination.42 Fig. 4(d) shows the PL patterns of different samples. The PL value of CdS reaches the highest value near 540 nm, at which the carrier recombination rate is the largest, and the position of the peak appearance is positively shifted after the complexation of In2S3, which occurs near 580 nm. After the complexation of In<sub>2</sub>S<sub>3</sub>, the peak appears positively shifted. It is noteworthy that the intensity of the PL peak of CdS/In<sub>2</sub>S<sub>3</sub>-TC decreases, which is related to its large specific surface area and smooth surface, where more active sites are formed on the highly exposed contact surface, while the smooth surface reduces the surface defects and less carriers recombine.

The SPV technique was used to respond to the surface charge nature of the sample, which can indicate the information between the surface charge accumulation of the sample and the wavelength of the incident light, the greater the degree of SPV response, the higher the efficiency of the photogenerated charge separation.<sup>24</sup> The positive value of the SPV in Fig. 5(a) indicates that the holes migrate to the surface, and the sample

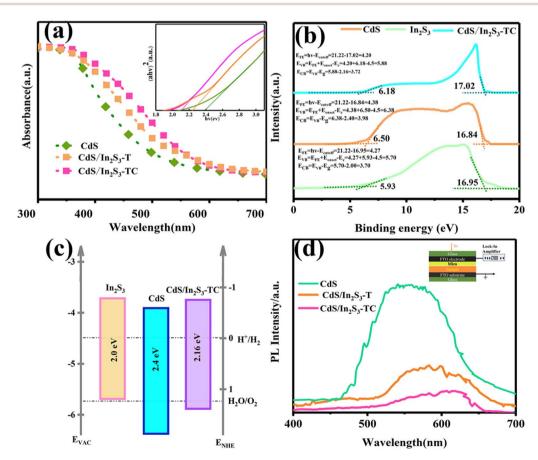


Fig. 4 UV-vis absorption spectrum (a), UPS (b), band patterns (c), and PL (d) of different samples.

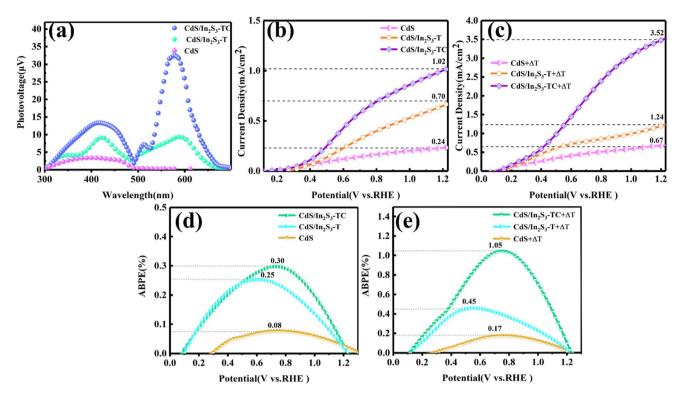


Fig. 5 SPV (a), LSV (b), ABPE (d) of different samples under photoelectrocatalytic conditions, LSV (c), ABPE (e) of different samples under pyrophotoelectrocatalytic conditions.

has an n-type property. Photoelectrodes are predominantly electron-conducting and react with oxygen, so this paper focuses on the water oxidation in Pyro-PEC systems of CdS photoelectrodes before and after modification. The CdS/In<sub>2</sub>S<sub>3</sub>-T specimen exhibited a strong diffraction peak at 300-500 nm; this is due to the strong light absorption ability of CdS in this region, and a new diffraction peak appears at 500 nm-700 nm, which is due to the strong light absorption ability of In<sub>2</sub>S<sub>3</sub> in this region. It is noteworthy that in CdS/In<sub>2</sub>S<sub>3</sub>-TC, a new small diffraction peak appears between 500 and 550 nm, which is caused by the appearance of a new phase within In<sub>2</sub>S<sub>3</sub>. The increased intensity of the diffraction peak of CdS/In<sub>2</sub>S<sub>3</sub>-TC indicates that more holes are accumulating on the surface, and the holes on the surface of the material are involved in the catalytic chemical reaction, which improves the surface energy.

The electrochemical characterization was carried out using a three-electrode electrochemical workstation of model CHI760E with 0.5 M  $Na_2SO_4$  (pH = 6.8) as the electrolyte, a xenon lamp (Perfect Light, CHF-XM500, 100 mW cm<sup>-2</sup>) as the external light source, and a water bath as the external drive for the hot-cold cycle. Fig. 5(b and c) shows the linear scanning voltammetry (LSV) curves of the samples at different levels of modification, and the correlation of the potential with the reversible hydrogen electrode (RHE) is calculated by Nernst equation eqn (S5).†43 Fig. 5(b) shows the LSV of different samples under photoelectrocatalytic conditions. The current density gradually increases with the increase of the applied bias voltage, and at 1.23 V vs. RHE, the current density is 0.24 mA  ${\rm cm}^{-2}$  for CdS, 0.70 mA cm<sup>-2</sup> for CdS/In<sub>2</sub>S<sub>3</sub>-T, and 1.02 mA cm<sup>-2</sup>,

the increase in current density indicates that the formation of CdS/In<sub>2</sub>S<sub>3</sub> can significantly optimize the carrier density of the CdS photoelectrode, and the phase engineering leads to further enhancement of the CdS/In<sub>2</sub>S<sub>3</sub> carrier density. This phenomenon verifies that the enriched phase structure and boundaries have an enhancing effect on the photoelectrode PEC performance. The LSV after the introduction of hot-cold cycling shows a similar trend to that before the introduction, and the current density of CdS/In<sub>2</sub>S<sub>3</sub>-TC reaches a maximum value of 3.52 mA cm $^{-2}$  at 1.23 V vs. RHE. This result verifies that the change of the phase structure affects the internal structure of crystals, which influences the pyroelectric performance of crystals. The LSV curves under photoelectrocatalytic and pyrophotoelectrocatalytic conditions are shown in Fig. S3,† which demonstrate the synergistic effect of pyroelectric and phase engineering on the enhancement of CdS carrier density. The applied bias photon current efficiency (ABPE) was calculated according to eqn (S6)† and the results are shown in Fig. 5(d and e), respectively.44 Fig. 5(d) shows that the ABPE values of different samples under photoelectrocatalytic conditions reach a maximum value around 0.8 eV, where CdS/In<sub>2</sub>S<sub>3</sub>-TC reaches 0.30%, and when hot-cold cycles are introduced, the maximum value of CdS/In<sub>2</sub>S<sub>3</sub>-TC reaches 1.05% in Fig. 5(e), meanwhile, the onset potential decreases. It indicates that phase engineering plays an important role in enhancing the photon conversion to electron capability, and a current response occurs when a small bias voltage is applied. The conversion of CdS/ In<sub>2</sub>S<sub>3</sub>-TC was further improved after the introduction of a temperature field. The ABPE values of the photoelectrodes

before and after modification and temperature field introduction are shown in Fig. S4† indicating that the CdS/In $_2$ S $_3$  composites with a rich phase structure and pyroelectric effect played an effective role in enhancing the CdS photoelectrode in the surface oxidation reaction. $^{41}$ 

Incident light to current conversion efficiency (IPCE) measurements were used to evaluate the contribution of monochromatic light to the current. The IPCE of various samples at a bias voltage of 1.23 V vs. RHE is shown in Fig. 6 according to eqn (S7),† and the photoelectrode peaks before and after modification all appear near 400 nm, which is consistent with the UV-visible spectral light absorption range. The maximum value of CdS/In<sub>2</sub>S<sub>3</sub>-TC reaches 30.24% in Fig. 6(a), which is indicative of the fact that the CdS/In<sub>2</sub>S<sub>3</sub> composites with phase engineering can realize the solarhydrogen conversion at a longer wavelength range. The PEC performance is significantly enhanced after the introduction of the temperature field. Specifically, the IPCE of CdS/In<sub>2</sub>S<sub>3</sub>-T reaches 46.78% and that of CdS/In<sub>2</sub>S<sub>3</sub>-TC reaches 55.91% in Fig. 6(b), this is because of the introduction of In<sub>2</sub>S<sub>3</sub> heterophase junctions, where more active sites exist at the heterophase boundary, reducing carrier complexation.45 The IPCE values of the photoelectrodes before and after modification and temperature field introduction are shown in Fig. S5.†

Electrochemical impedance spectroscopy (EIS) is commonly used to obtain the charge transfer capacity at the interface between the photoelectrode and the electrolyte, and can be used to characterize the kinetics of charge, which is of great value in PEC systems. <sup>46</sup> The EIS curves were tested at -1–1 V  $\nu s$ . Ag/AgCl. The equivalent circuit model is shown in the inset of Fig. 7(a), where  $R_s$  is the series resistance, and  $R_{\rm et}$  and CPE are the charge-transfer resistance and constant-phase element at the electrode/electrolyte interface, respectively. The smaller the semicircle, the lower the transfer resistance and the greater the charge transfer capability. Fig. 7(a) shows that the resistance to charge migration is reduced after the formation of CdS/In<sub>2</sub>S<sub>3</sub>, and the

internal mechanism diagram is shown in Fig. S6.† The formation of a heterojunction led to more active interfaces which established more carrier transport channels and optimized the surface dynamics. Notably, the semicircle of CdS/In<sub>2</sub>S<sub>3</sub>-TC becomes smaller, which is related to the formation of the In<sub>2</sub>S<sub>3</sub> heterophase junction, and the presence of active sites for effective charge exchange at the heterophase boundary improves the hole transport efficiency at the photoelectrode/ electrolyte interface. The semicircle of CdS/In<sub>2</sub>S<sub>3</sub>-TC is minimized after the external temperature field increases the driving force, the pyroelectric effect converts the thermal energy into a built-in electric field, the carrier transfer process obtains a larger driving force, and the atoms at the phase boundaries can be highly activated by the localized charge accumulation, which improves the charge transfer capability.

In addition to characterizing the dynamics of carrier migration, Mott-Schottky diagrams at a frequency of 1 kHz under photoelectric and pyro-photoelectrocatalytic conditions were tested as in Fig. 7(c and d) to characterize the carrier density  $(N_d)$  and flat band potential  $(V_{fb})$  according to eqn (S8) and (S9).† The positive slope in the figure indicates that the photoelectrodes have n-type characteristics.  $N_{\rm d}$  and  $V_{\rm fb}$  can be calculated according to the following two equations and the results are shown in Table S1 in the ESI.† The modification strategies decrease the slope, and increase the donor density, and the aggregation of more carriers reduces the energy band bending at the interface and shifts the position of the Fermi energy level upwards. The Schottky barrier is related to the local stress field generated by the polarization electric field, which is excited by the internal polarization electric field of the pyroelectric material when a temperature field is introduced. This is well confirmed by the comparison of Fig. 7(c) and (d), where the flat-band potentials of all types of photoelectrodes are negatively shifted by the temperature field, the built-in electric field strength increases, and the surface state and interfacial barriers decrease. The heterostructure of CdS/In2S3-TC exhibits

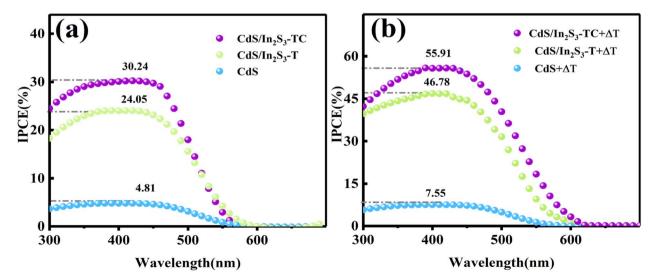


Fig. 6 IPCE of different samples under photoelectrocatalytic conditions (a), and pyro-photoelectrocatalytic conditions (b).

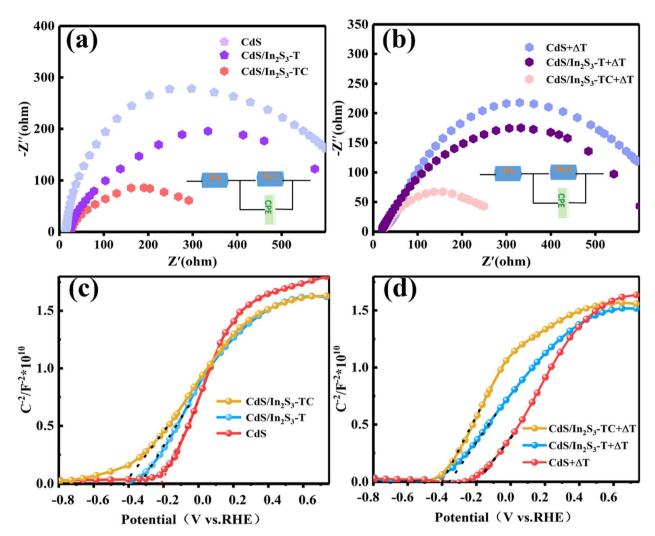


Fig. 7 EIS (a) and Mott-Schottky (c) of different samples under photoelectrocatalytic conditions (a), EIS (b) and Mott-Schottky (d) of different samples under pyro-photoelectrocatalytic conditions.

modulation effects, eliminates space charge defects and optimizes pyroelectricity, which results in more efficient charge transfer.

In order to understand the effect of CdS/In<sub>2</sub>S<sub>3</sub> composites and phase engineering on the pyroelectric properties and the photoelectric performance of the electrode materials, the I-T curves of 1.23 V vs. RHE under different conditions were tested. Fig. 8(a) shows the curve of current density with time under the temperature field of hot-cold cycles, and the ideal temperature variation curve as shown in Fig. 8(b). As can be seen in Fig. 8(a), the current density occurs during both the heating and cooling phases, showing the shape of a cyclic triangle. When the temperature changes, the positions of the atoms in the crystal structure change, and the bound and externally compensated charges are in a state of imbalance, which promotes the oxidation reactions during the process of charge balance. The mechanism is illustrated in Fig. S7.† When the temperature remains constant, there exists an equilibrium between the bound charge and the external compensating charge. However, with an increase in temperature, there is a shift in the position

of atoms within the crystal structure, resulting in a decrease in the electric dipole moment and subsequently reducing the number of internal bound charges. Consequently, this leads to a chemical reaction of the electrolyte surrounding the excess compensating charge on the crystal surface. Under constant temperature conditions, the bound charge and the compensating charge remain in equilibrium, causing a consistent decrease in current due to the reduction in both internal and external charges. Conversely, as the temperature decreases, the alteration in the internal polarization field augments the number of bound charges. Simultaneously, compensating charges in the electrolyte migrate towards the material's surface. Consequently, the macroscopic manifestation of temperature change is reflected as an increase in current. The photoelectrodes before and after the modification show a perfect pyroelectric effect. This might be due to the critical size effect, tetragonal phase in the surface of the complex lattice structure and the influence of the external environment. The ferroelectricity at the interface is weakened and affects the polarization strength at the surface. When the partially

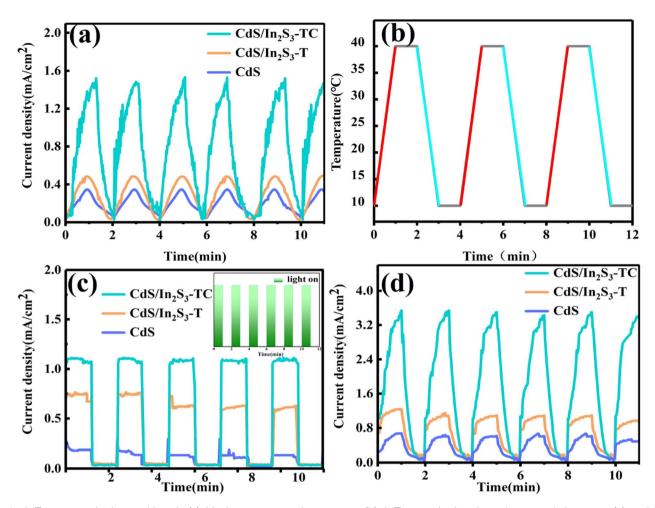


Fig. 8 I-T curves under hot-cold cycle (a), ideal temperature change curve (b), I-T curves in the photoelectrocatalytic system (c), and I-Tcurves in the pyro-photoelectrocatalytic system (d).

structured tetragonal phase is transformed into a cubic phase, the transformation of the phase structure at the surface alters the depolarization field strength, which changes the critical size effect on the internal polarized electric field, and CdS/In<sub>2</sub>S<sub>3</sub>-TC exhibits superior pyroelectric properties. As can be seen from Fig. 8(c), CdS/In<sub>2</sub>S<sub>3</sub>-TC also exhibits better photovoltaic performance, which is related to its greater light response characteristics, as well as an increase in the number of interfaces, which form active sites favorable to the catalyst's performance in the light response properties. Fig. 8(d) shows the *I-T* curves under pyro-photoelectrocatalytic conditions, and CdS/In<sub>2</sub>S<sub>3</sub>-TC still exhibits the best pyro-photoelectrocatalytic performance, and to probe the internal polarization field conditions, we performed PFM tests.

The atomic level morphology, electrical domains and phase structure were probed with the PFM light tapping mode, the temperature was raised to 50 °C in an oven before testing. 47 The morphology and microscopic domains of the 5  $\mu$ m  $\times$  5  $\mu$ m photoelectrode are characterized by PFM in Fig. 9. Comparison of the morphology of CdS/In<sub>2</sub>S<sub>3</sub>-T and CdS/In<sub>2</sub>S<sub>3</sub>-TC (Fig. 9(a and e)) shows that the size of the multiphase structured photoelectrode decreases and the specific surface area increases,

which can be well confirmed by the 3D image. In general, the size of the crystal is closely related to the structure of the domains, and as the grain size decreases, the size of the ferroelectric domains decreases as well, which lowers the polarization reversal barriers and promotes polarization reversal, which in turn improves the pyroelectric effect. The amplitude image (Fig. 9(c and g)) clearly shows the morphology of the photoelectrode-rich ferroelectric domains, with the domain walls shown as darker lines, with light and dark representing the polarization strength. During the test, the polarity within the material changes. This is due to the spontaneous polarization modulating the neighboring atomic arrangement and structure, and CdS/In<sub>2</sub>S<sub>3</sub>-TC exhibits pronounced polarization intensity with distinct domain wall boundaries. The domains with polarization vectors on the sample surface correspond to pronounced phase deflections, as can be seen in the phase images (Fig. 9(d and h)), where CdS/ In<sub>2</sub>S<sub>3</sub>-TC exhibits a more pronounced linear color change and a rich polarization direction. Meanwhile, the ferroelectric hysteresis behavior of the photoelectrode was investigated as shown in Fig. S8, $\dagger$  with a bias voltage between -10 V and 10 V. Clear single hysteresis loops and butterfly-shaped hysteresis

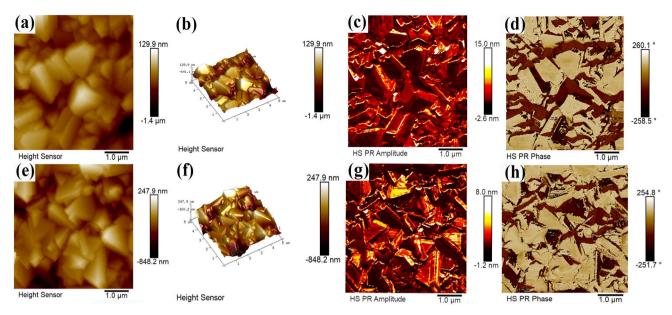


Fig. 9 PFM micrographs, 3D image, the relative amplitude image, and phase image of CdS/In<sub>2</sub>S<sub>3</sub>-T (a-d) and CdS/In<sub>2</sub>S<sub>3</sub>-TC (e-h).

loops are observed in the phase and amplitude spectra, respectively, which fully demonstrate that the spontaneous polarization shows ferroelectric switching behavior. Among them, the CdS/In<sub>2</sub>S<sub>3</sub>-TC amplitude response shows that the butterfly ring opens at 0.95 V, while the phase also switches 180° at 0.95 V.

After the separation of electrons and holes, they need to migrate in the bulk and on the surface to participate in the reaction at the active surface, and the transport efficiency is hampered by recombination and resistance in this process.<sup>48</sup> To quantitatively characterize the carrier separation efficiency inside the photoelectrode, 0.25 M Na<sub>2</sub>SO<sub>3</sub> was added to 0.5 M Na<sub>2</sub>SO<sub>4</sub> as a cavity scavenger. The charge separation efficiencies were calculated separately for the surface  $(\eta_{surface})$  and bulk  $(\eta_{\text{bulk}})$  in Fig. 10(a and b), the calculation process is given in eqn (S10).† After adding 0.25 M Na<sub>2</sub>SO<sub>3</sub> as the hole scavenger in 0.5 M Na<sub>2</sub>SO<sub>4</sub>, surface recombination of carriers is inhibited, and  $\eta_{\text{surface}}$  can be considered for 100%. Therefore, in the case of hole scavenger addition, the photocurrent density is decided by eqn (S11),† the  $\eta_{\text{bulk}}$  and  $\eta_{\text{surface}}$  are calculated by eqn (S12) and (S13).† The  $\eta_{\rm bulk}$  and  $\eta_{\rm surface}$  of CdS at 1.23 V  $\nu s$ . RHE are 8.43% and 14.47%, respectively, with low separation efficiency, indicating severe carrier recombination. After the phase engineering, the carriers can be separated and transferred effectively, and the  $\eta_{\text{bulk}}$  is increased from 14.47% to 36.95%,  $\eta_{\text{surface}}$ is increased from 8.43% to 22.14%. This is related to the altered electron transfer channel, which lowers the separation barrier. In addition to this, Fig. 10(c) shows the Bode phase diagram of CdS/In<sub>2</sub>S<sub>3</sub>-TC. The frequency of peaks in CdS/In<sub>2</sub>S<sub>3</sub>-TC is lower than that of the other samples, suggesting that it has a longer carrier lifetime.49 After the introduction of the temperature field, the  $\eta_{\text{bulk}}$  of CdS/In<sub>2</sub>S<sub>3</sub>-TC was increased to 63.98% and the  $\eta_{\text{surface}}$  was increased to 45.00%. This encouraging improvement is extremely important and linked

to the enhancement of pyroelectric performance, where the optimization of the internal electric field improves the conductivity of the photoelectrode and reduces the charge recombination improving the charge transfer efficiency, more holes are transferred from the surface of the catalyst to the electrolyte, thus facilitating the reaction.

The stability of photoelectrodes is an important reference performance in the practical application of PEC, for this reason we tested the stability of the samples before and after modification under 240 min of continuous light as shown in Fig. 10(d). The stability of CdS is poor, and the current density of the sample starts to decrease from 0.24 mA cm<sup>-2</sup> to 0.11 mA cm<sup>-2</sup> after being irradiated by light. When attaching the cubic phase In<sub>2</sub>S<sub>3</sub> to form CdS/In<sub>2</sub>S<sub>3</sub>-T, the current density of 0.70 mA cm<sup>-2</sup> decreases to 0.60 mA cm<sup>-2</sup> and then tends to stabilize. CdS/ In<sub>2</sub>S<sub>3</sub>-TC was further stabilized, and after 1.5 G of light irradiation, the current density changed slightly and the stability was significantly improved achieving satisfactory results.

The sample after the stability test was characterized in Fig. S9,† some of the particle morphology of CdS/In<sub>2</sub>S<sub>3</sub>-T was corroded and the boundaries were dislodged during the reaction process, while the morphology of CdS/In<sub>2</sub>S<sub>3</sub>-TC did not undergo obvious change, suggesting that the stability was improved.

Subsequently, the oxygen precipitation capacity of the CdS/ In<sub>2</sub>S<sub>3</sub>-TC photoelectrode was quantitatively analyzed using gas chromatography, and the Faraday efficiency was calculated according to eqn (S14).†50 Fig. S10† shows that the O2 generation is enhanced after phase engineering modification, and the Faraday efficiencies of CdS/In<sub>2</sub>S<sub>3</sub>-T and CdS/In<sub>2</sub>S<sub>3</sub>-TC are around 91% and 94%, respectively. The phase engineering reduces the consumption of photogenerated holes by the photoanode, which in turn enhances the stability of the photoelectrode with a higher O2 generation.

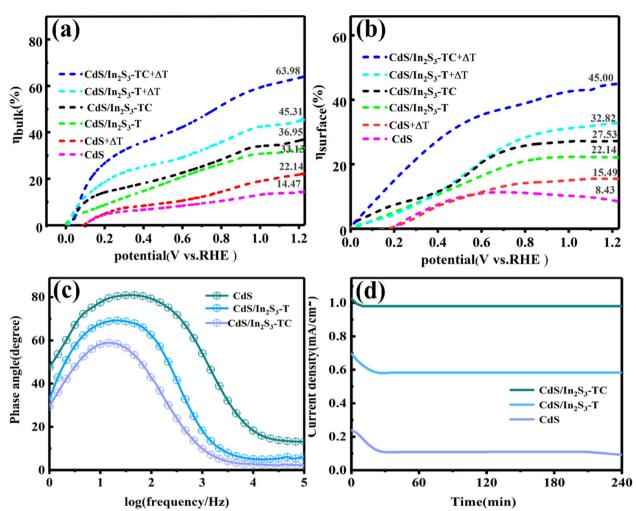


Fig. 10 The  $\eta_{\text{bulk}}$  (a),  $\eta_{\text{surface}}$  (b), Bode phase diagram (c), stability (d) of different samples.

# 4 Conclusion

In conclusion, in this paper, heterogeneous junctions were successfully formed by phase modification engineering, and the feasibility of introducing phase engineering to improve the Pyro-PEC performance of CdS/In<sub>2</sub>S<sub>3</sub> has been demonstrated in this paper. The CdS/In<sub>2</sub>S<sub>3</sub>-TC photoanode absorption edge produced by this strategy widens from 516 nm to 575 nm compared to CdS, achieves a charge separation efficiency of 55.91% at 1.23 V vs. RHE, and exhibits a high current density of 3.52 mA cm<sup>-2</sup> and further improved stability. The phasemodulated CdS/In<sub>2</sub>S<sub>3</sub> has abundant catalytic active sites at the boundary and active surfaces, which can promote the charge generation and transfer ability to significantly improve the photoelectrical performance. In addition, CdS/In<sub>2</sub>S<sub>3</sub>-TC exhibits good field effect modulation, which enhances the spontaneous polarization of the photoelectrode and improves the pyroelectric performance. This study achieves efficient Pyro-PEC water splitting performance by adjusting phase structures on the photoanode, and provides a new idea for the regulation of the polarization electric field.

# Author contributions

Xingfei Chen, Zhifeng Liu, Mengnan Ruan, Chengyi Wang, and Tingting Zhong conceived and designed the study. Xingfei Chen performed the experiments. Xingfei Chen, Zhifeng Liu, Mengnan Ruan, Chengyi, and Tingting Zhong wrote the paper. Xingfei Chen, Zhifeng Liu, and Mengnan Ruan, reviewed and edited the manuscript. Xingfei Chen, Chengyi, and Tingting Zhong validated the results. All authors read and approved the manuscript.

# Conflicts of interest

There are no conflicts to declare.

# Acknowledgements

The authors gratefully acknowledge the financial support from the National Natural Science Foundation of China (No. 52373301 and 52073200).

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